

Vishay Siliconix

# N-Channel 30 V (D-S) MOSFET

### **DESCRIPTION**

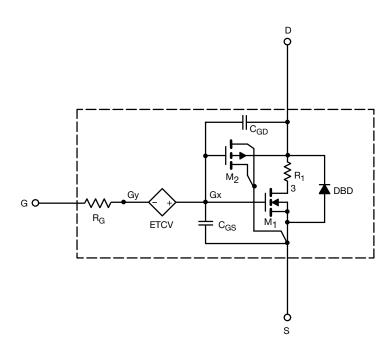
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -  $55\,^{\circ}$ C to +  $125\,^{\circ}$ C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### SUBCIRCUIT MODEL SCHEMATIC

### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- · Model the Gate Charge



#### Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



# **SPICE Device Model SiS476DN**

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<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.3	-	V
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 15 A	0.00203	0.00205	Ω
		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 10 A	0.00277	0.00275	
Forward Transconductance <sup>a</sup>	9fs	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 15 A	86	105	S
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = 5 A	0.73	0.73	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1 MHz	3600	3595	pF
Output Capacitance	C <sub>oss</sub>		1090	1040	
Reverse Transfer Capacitance	C <sub>rss</sub>		83	79	
Total Gate Charge	Qg	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 10 A	46	51	nC
		V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 4.5, I <sub>D</sub> = 10 A	22	22.5	
Gate-Source Charge	Q <sub>gs</sub>		8.6	8.6	
Gate-Drain Charge	Q <sub>gd</sub>		4	4	

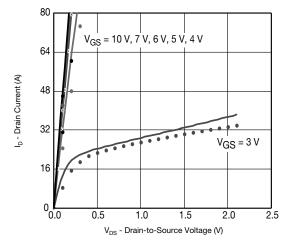
#### **Notes**

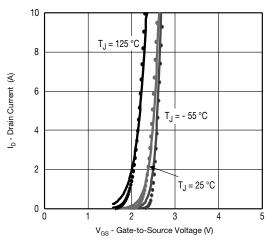
- a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

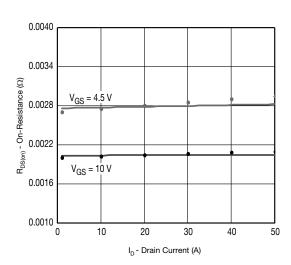
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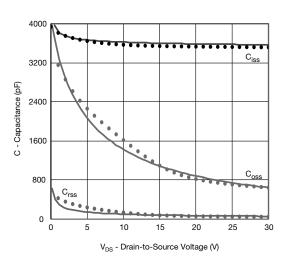
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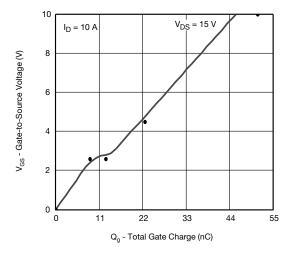
## COMPARISON OF MODEL WITH MEASURED DATA $T_J = 25~^{\circ}\text{C}$ , unless otherwise noted

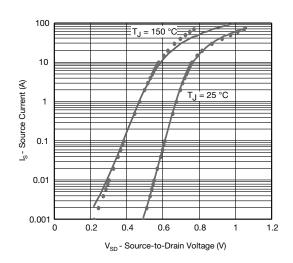












#### Note

• Dots and squares represent measured data.



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